

SCT3080AL N-channel SiC power MOSFET

V _{DSS}	650V
R _{DS(on)} (Typ.)	80mΩ
I_{D}^{*1}	30A
P _D	134W

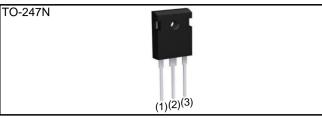
Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Fast reverse recovery
- 4) Easy to parallel
- 5) Simple to drive
- 6) Pb-free lead plating ; RoHS compliant

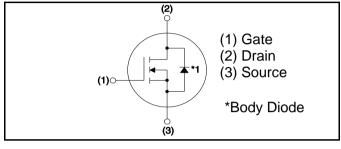
Application

- \cdot Solar inverters
- DC/DC converters
- Switch mode power supplies
- Induction heating
- Motor drives

Outline



Inner circuit



Packaging specifications

	Packing	Tube
	Reel size (mm)	-
Tuno	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	30
	Taping code	C11
	Marking	SCT3080AL

●Absolute maximum ratings (T_{vj} = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit	
Drain - Source Voltage		V _{DSS}	650	V	
Continuous Drain current	$T_c = 25^{\circ}C$	I _D ^{*1}	30	А	
Continuous Drain current	T _c = 100°C	I _D ^{*1}	21	А	
Pulsed Drain current ($T_c = 25^{\circ}C$)		I _{D,pulse} ^{*2}	75	А	
Gate - Source voltage (DC)		V _{GSS}	-4 to +22	V	
Gate - Source surge voltage (t _{surge} < 300nsec)		V _{GSS_surge} *3	-4 to +26	V	
Recommended drive voltage		V _{GS_op} ^{*4}	0 / +18	V	
Virtual Junction temperature		T _{vj}	175	°C	
Range of storage temperature		T _{stg}	-55 to +175	°C	

•Electrical characteristics ($T_{vj} = 25^{\circ}C$ unless otherwise specified)

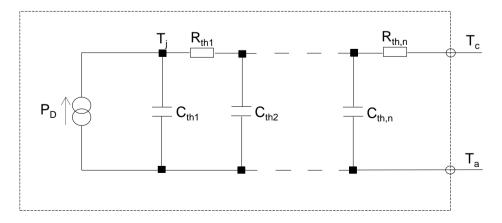
Doromotor	Symbol	Conditions		Unit			
Parameter	Symbol Conditions –		Min.	Тур.	Max.	Offic	
		$V_{GS} = 0V, I_D = 1mA$					
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$T_{vj} = 25^{\circ}C$	650	-	-	V	
		T _{vj} = -55°C	650	-	-		
		$V_{GS} = 0V, V_{DS} = 650V$					
Zero Gate voltage Drain current	I _{DSS}	$T_{vj} = 25^{\circ}C$	-	1	10	μA	
		T _{vj} = 150°C	-	2	-		
Gate - Source leakage current	I _{GSS+}	$V_{GS} = +22V$, $V_{DS} = 0V$	-	-	100	nA	
Gate - Source leakage current	I _{GSS-}	$V_{GS} = -4V , V_{DS} = 0V$	-	-	-100	nA	
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = 10V, I_D = 5mA$	2.7	-	5.6	V	
		V _{GS} = 18V, I _D = 10A					
Static Drain - Source on - state resistance	${\sf R}_{\sf DS(on)}$ *5	T _{vj} = 25°C	-	80	104	mΩ	
		T _{vj} = 150°C	-	115	-		
Gate input resistance	R_G	f = 1MHz, open drain	-	13	-	Ω	

Thermal resistance

Parameter	Symbol	Values			Unit
Falanletei	Symbol	Min.	Тур.	Max.	Onit
Thermal resistance, junction - case	R _{thJC}	-	0.86	1.12	K/W

•Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R _{th1}	1.17E-01		C _{th1}	6.82E-04	
R _{th2}	7.29E-01	K/W	C _{th2}	5.28E-03	Ws/K
R _{th3}	1.30E-02		C _{th3}	6.78E-01	





•Electrical characteristics (T_{vj} = 25°C unless otherwise specified)

Parameter	Symbol	rmbol Conditions		Values		Unit
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Transconductance	g _{fs} ^{∗5}	$V_{DS} = 10V, I_{D} = 10A$	-	3.8	-	S
Input capacitance	C _{iss}	$V_{GS} = 0V$	-	571	-	
Output capacitance	C _{oss}	V _{DS} = 500V	-	39	-	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	19	-	
Effective output capacitance, energy related	C _{o(er)}	$V_{GS} = 0V$ $V_{DS} = 0V$ to 300V	-	99	-	pF
Total Gate charge	Q_g^{*5}	$V_{DS} = 300V$ $I_{D} = 10A$	-	48	-	
Gate - Source charge	Q _{gs} *5	$V_{GS} = 18V$	-	10	-	nC
Gate - Drain charge	Q_{gd} *5	See Fig. 1-1.	-	25	-	
Turn - on delay time	t _{d(on)} *5	$V_{DS} = 300V$ $I_{D} = 10A$	-	16	-	
Rise time	t _r *5	V _{GS} = 0V/+18V	-	26	-	ns
Turn - off delay time	t _{d(off)} *5	$R_{G} = 0\Omega$ $R_{L} = 30\Omega$	-	27	-	115
Fall time	t _f *5	See Fig. 1-1, 1-2.	-	16	-	
Turn - on switching loss	E _{on} *5	$V_{DS} = 300V$ $V_{GS}=0V/18V, I_{D} = 10A$ $R_{G} = 0\Omega, L = 500\mu H$	-	41	-	
Turn - off switching loss	E _{off} *5	E_{on} includes diode reverse recovery $L_{\sigma} = 50$ nH, $C_{\sigma} = 200$ pF See Fig. 2-1, 2-2.	-	15	-	Lμ



SCT3080AL

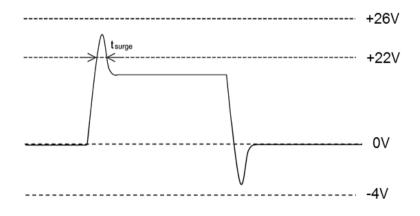
●Body diode electrical characteristics (Source-Drain) (T_{vj} = 25°C unless otherwise specified)

Parameter	Symbol	Conditions		Values		Unit
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Onit
Body diode continuous, forward current	ا _S *1	T _c = 25°C	-	-	30	А
Body diode direct current, pulsed	I_{SM} *2	T _c = 25 0	-	-	75	А
Forward voltage	V_{SD} *5	$V_{GS} = 0V, I_{S} = 10A$	-	3.2	-	V
Reverse recovery time	t _{rr} *5	$I_F = 10A$ $V_R = 300V$	-	15	-	ns
Reverse recovery charge	Q _{rr} *5	v _R = 300∨ di/dt = 1100A/µs	-	53	-	nC
Peak reverse recovery current	I _{rrm} *5	$L_{\sigma} = 50$ nH, $C_{\sigma} = 200$ pF See Fig. 3-1, 3-2.	-	7	-	А

*1 Limited by maximum T_{vj} and for Max. R_{thJC} .

*2 PW \leq 10µs, Duty cycle \leq 1%

*3 Example of acceptable V_{GS} waveform



- *4 Please be advised not to use SiC-MOSFETs with V_{GS} below 13V as doing so may cause thermal runaway.
- *5 Pulsed



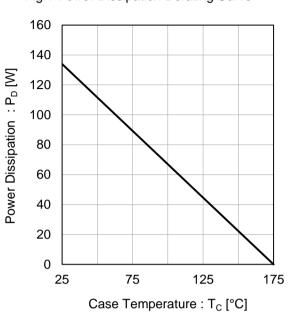
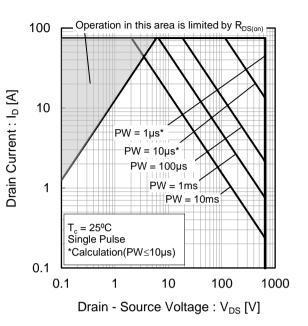
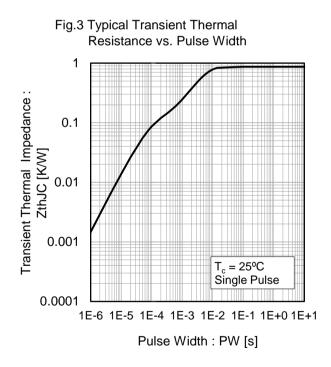


Fig.1 Power Dissipation Derating Curve

Fig.2 Maximum Safe Operating Area







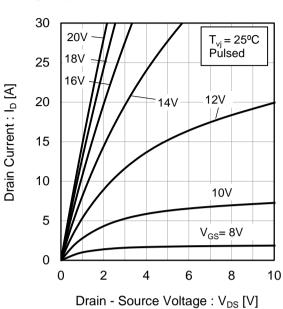


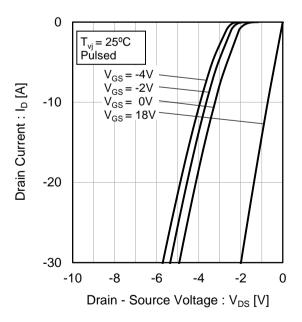
Fig.4 Typical Output Characteristics(I)

15 20V 18V 16V 14V $T_{vj} = 25^{\circ}C$ Drain Current : I_D [A] 10 Pulsed 12V 10V 5 $V_{GS} = 8V$ 0 0 1 2 3 4 5

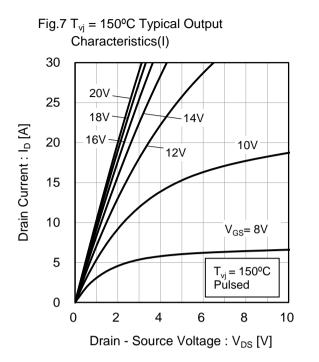
Fig.5 Typical Output Characteristics(II)

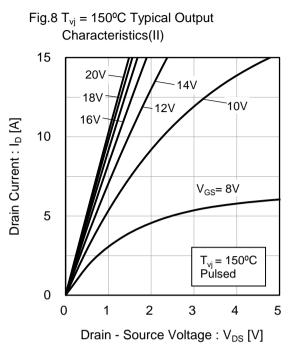
Drain - Source Voltage : V_{DS} [V]

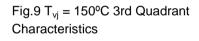
Fig.6 T_{vj} = 25°C 3rd Quadrant Characteristics

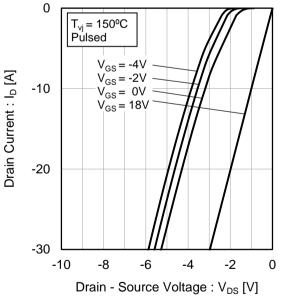


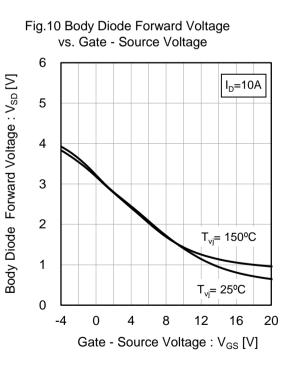














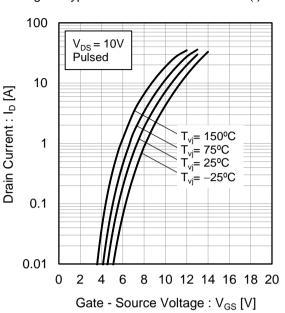


Fig.11 Typical Transfer Characteristics (I)

Fig.12 Typical Transfer Characteristics (II)

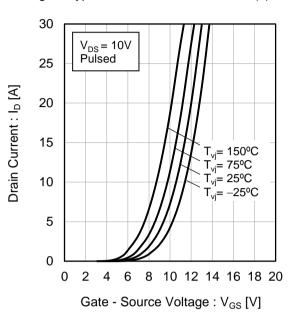
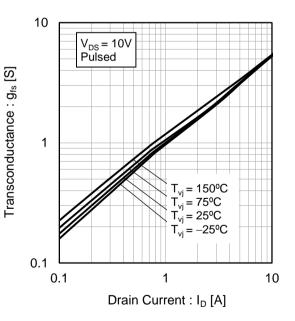
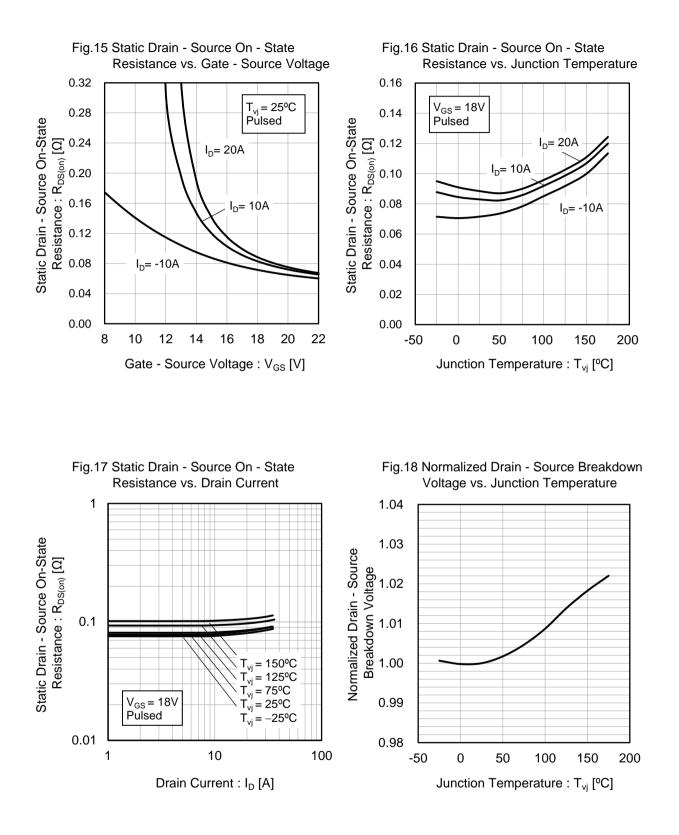


Fig.13 Gate Threshold Voltage vs. Junction Temperature 6 $V_{DS} = 10V$ $I_{D} = 5mA$ Gate Threshold Voltage : V _{GS(th)} [V] 5 4 3 2 1 0 0 50 100 200 -50 150 Junction Temperature : T_{vj} [°C]

Fig.14 Transconductance vs. Drain Current









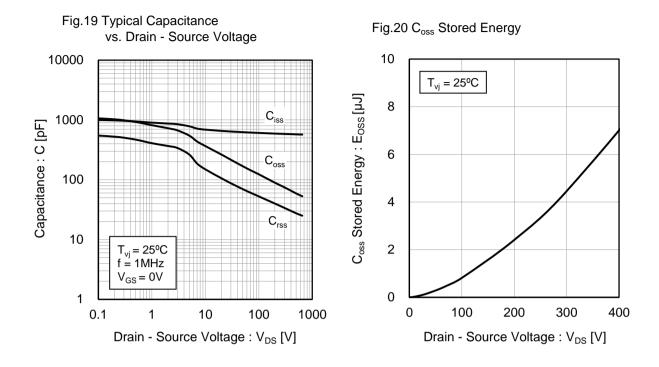
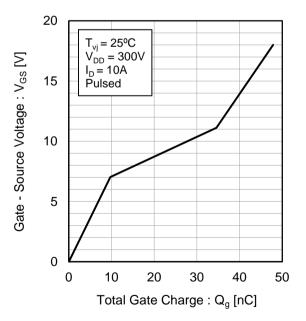
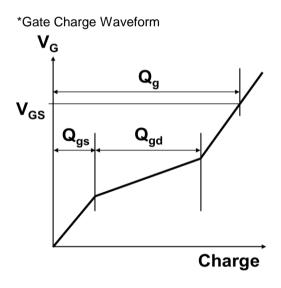
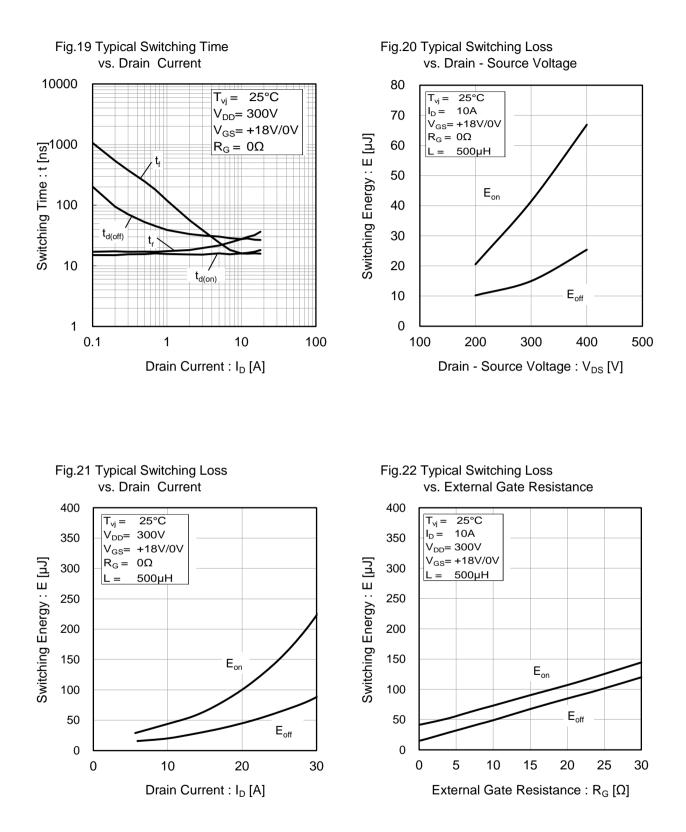


Fig.21 Dynamic Input Characteristics











Measurement circuits and waveforms

Fig.1-1 Gate Charge and Switching Time Measurement Circuit

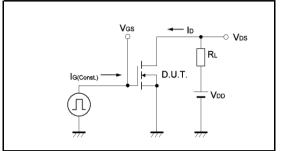


Fig.2-1 Switching Energy Measurement Circuit

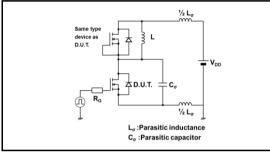


Fig.3-1 Reverse Recovery Time Measurement Circuit

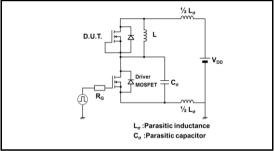


Fig.1-2 Waveforms for Switching Time

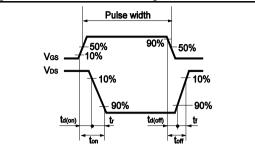


Fig.2-2 Waveforms for Switching Energy Loss

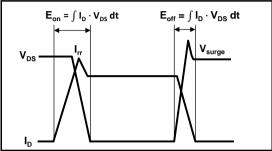
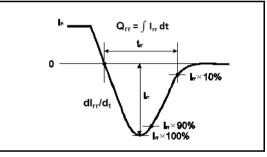
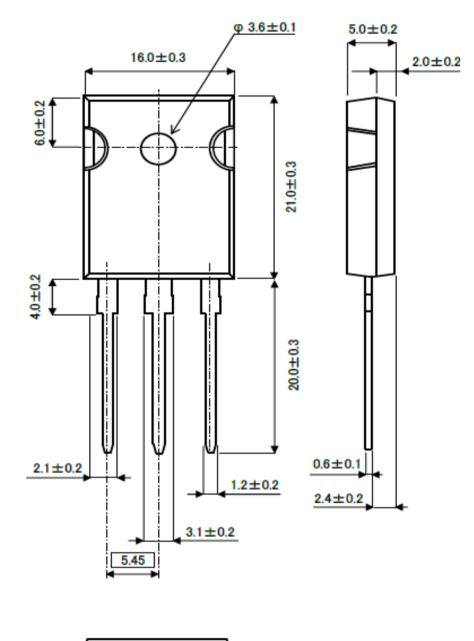


Fig.3-2 Reverse Recovery Waveform





Package Dimensions

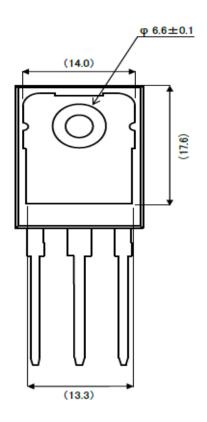




Unit: mm





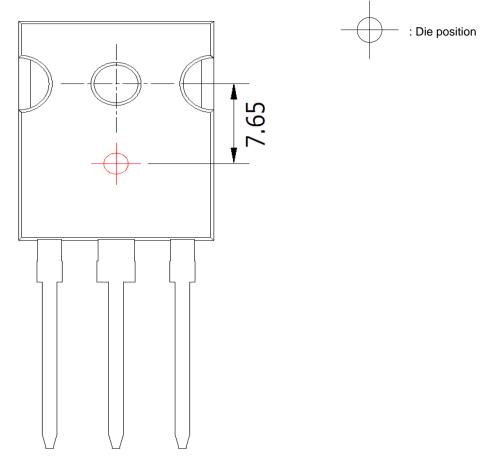


Unit: mm





Die Bonding Layout



•Front view of the packaging.

•Dimensions are design values.

·If the heat sink is to be installed, it should be in contact with the die bonding point.

Unit: mm





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